

	L #	Hits	Search Text	DBs
1	L1	3598	((organo or organic) adj (electroluminesc\$8 or el or light adj emit\$6) or organoelectro\$ or oel or oeld or oled).ti,ab.	US-PGPUB ; USPAT
2	L2	124	((organo or organic) adj electro adj luminesc\$8).ti,ab.	US-PGPUB ; USPAT
3	L3	235763	(insulat\$6 or fill\$4).ti,ab.	US-PGPUB ; USPAT
4	L4	151202	(electrode or anode).ti,ab.	US-PGPUB ; USPAT
5	L5	22971	3 with 4	US-PGPUB ; USPAT
6	L6	225	(1 or 2) and 5	US-PGPUB ; USPAT
7	L7	43343	liftoff or lift\$4 adj off	US-PGPUB ; USPAT
8	L8	26	6 and 7	US-PGPUB ; USPAT
9	L9	303922	resist or photoresist	US-PGPUB ; USPAT
10	L10	137141	(conduct\$6 or ito or tin or electrode or anode) same etch\$4	US-PGPUB ; USPAT
11	L11	19179	(insulat\$6 or fill\$4) same 9 same 10	US-PGPUB ; USPAT
12	L12	45	6 and 11	US-PGPUB ; USPAT

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13	L13	159115	(flat\$4 or smooth\$4 or planar\$8).ti,ab.	US-PGPUB ; USPAT
14	L14	20	6 and 13	US-PGPUB ; USPAT
15	L15	64563	(insulat\$6 or fill\$4) same 10	US-PGPUB ; USPAT
16	L16	9806	(plasma or chamber) same 15	US-PGPUB ; USPAT
17	L17	22	6 and 16	US-PGPUB ; USPAT
18	L18	154431	(insulat\$6 or fill\$4) same deposit\$6	US-PGPUB ; USPAT
19	L19	845	10 same 18 same chamber	US-PGPUB ; USPAT
20	L20	3	6 and 19	US-PGPUB ; USPAT
21	L21	2169	313/504.ccls.	US-PGPUB ; USPAT
22	L22	110	21 and (7 or 11 or 16 or 19)	US-PGPUB ; USPAT
23	L23	86	22 not (8 or 12 or 14 or 17 or 20)	US-PGPUB ; USPAT
24	L24	3077	430/314,319,321.ccls.	US-PGPUB ; USPAT

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25	L25	59	(1 or 2) and 24	US-PGPUB ; USPAT
26	L26	53	25 not (22 or 8 or 12 or 14 or 17 or 20)	US-PGPUB ; USPAT
27	L27	46	tada-hiroshi.in.	US-PGPUB ; USPAT
28	L28	78	oda-atsushi.in.	US-PGPUB ; USPAT
29	L29	95	ishikawa-hitoshi.in.	US-PGPUB ; USPAT
30	L30	56	toguchi-satoru.in.	US-PGPUB ; USPAT
31	L31	55	(27 or 28 or 29 or 30) and (1 or 2)	US-PGPUB ; USPAT
32	L32	20530	(organo or organic) adj (electroluminesc\$8 or el or light adj emit\$6) or organoelectro\$ or oel or oeld or oled	EPO; JPO; DERW ENT; IBM_T DB
33	L33	754	(organo or organic) adj electro adj luminesc\$8	EPO; JPO; DERW ENT; IBM_T DB
34	L34	86114	(conduct\$6 or ito or tin or electrode or anode) same etch\$4	EPO; JPO; DERW ENT; IBM_T DB

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35	L35	58884	(insulat\$6 or fill\$4) same deposit\$6	EPO; JPO; DERW ENT; IBM_T DB
36	L36	20	(32 or 33) and 34 and 35	EPO; JPO; DERW ENT; IBM_T DB
37	L37	101024 2	flat\$4 or smooth\$4 or planar\$8	EPO; JPO; DERW ENT; IBM_T DB
38	L38	481412	(conduct\$6 or ito or tin or electrode or anode) and (insulat\$8 or fill\$4)	EPO; JPO; DERW ENT; IBM_T DB
39	L39	242	(32 or 33) and 37 and 38	EPO; JPO; DERW ENT; IBM_T DB
40	L40	193478	resist or photoresist or liftoff or lift\$4 adj off	EPO; JPO; DERW ENT; IBM_T DB
41	L41	8	39 and 40	EPO; JPO; DERW ENT; IBM_T DB
42	L42	255146	etch\$4	EPO; JPO; DERW ENT; IBM_T DB

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43	L43	24	(32 or 33) and 38 and 40 and 42	EPO; JPO; DERW ENT; IBM_T DB
44	L44	107446 6	plasma or chamber	EPO; JPO; DERW ENT; IBM_T DB
45	L45	86	(32 or 33) and 38 and 44	EPO; JPO; DERW ENT; IBM_T DB
46	L46	82	45 not (43 or 41 or 36)	EPO; JPO; DERW ENT; IBM_T DB
47	L47	1270	deposit\$8 with 42 with chamber	EPO; JPO; DERW ENT; IBM_T DB
48	L48	0	(32 or 33) and 47	EPO; JPO; DERW ENT; IBM_T DB
49	L49	85	38 and 47	EPO; JPO; DERW ENT; IBM_T DB
50	L50	1086	"same" adj chamber	EPO; JPO; DERW ENT; IBM_T DB

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51	L51	10429	(single or one) adj chamber	EPO; JPO; DERW ENT; IBM_T DB
52	L52	23	deposit\$8 with 42 with (50 or 51)	EPO; JPO; DERW ENT; IBM_T DB
53	L55	33697	("same" or single or one) adj chamber	US- PGPUB ; USPAT
54	L56	30	10 same 18 same 55	US- PGPUB ; USPAT
55	L57	97622	(conduct\$6 or ito or tin or electrode or anode) with etch\$4	US- PGPUB ; USPAT
56	L58	101388	(insulat\$6 or fill\$4) with deposit\$6	US- PGPUB ; USPAT
57	L59	247710	plasma	US- PGPUB ; USPAT
58	L60	1771	57 same 58 same 59	US- PGPUB ; USPAT
59	L61	5	(1 or 2) and 60	US- PGPUB ; USPAT
60	L62	646	(etch\$4 with deposit\$8 with plasma).ti,ab.	US- PGPUB ; USPAT
61	L63	344150	(conduct\$6 or ito or tin or electrode or anode).ti,ab.	US- PGPUB ; USPAT

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62	L64	124910	insulat\$6.ti,ab.	US- PGPUB ; USPAT
63	L65	47	62 and 63 and 64	US- PGPUB ; USPAT
64	L67	345741	(conduct\$6 or ito or tin or electrode or anode) with (insulat\$8 or fill\$4)	EPO; JPO; DERW ENT; IBM_T DB
65	L68	76	(32 or 33) and (37 with 67)	EPO; JPO; DERW ENT; IBM_T DB
66	L70	51472	dielectric.ti,ab.	US- PGPUB ; USPAT
67	L71	9343	70 with 4	US- PGPUB ; USPAT
68	L72	12	(1 or 2) and 71	US- PGPUB ; USPAT
69	L74	7730	dielectric same 9 same 10	US- PGPUB ; USPAT
70	L77	5740	dielectric same 10 same (plasma or chamber)	US- PGPUB ; USPAT
71	L78	14	21 and (74 or 75)	US- PGPUB ; USPAT

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72	L79	224646	dielectric	EPO; JPO; DERW ENT; IBM_T DB
73	L80	18859	79 same deposit\$8	EPO; JPO; DERW ENT; IBM_T DB
74	L81	4	(32 or 33) and 34 and 80	EPO; JPO; DERW ENT; IBM_T DB
75	L82	117493	(conduct\$6 or ito or tin or electrode or anode) and dielectric	EPO; JPO; DERW ENT; IBM_T DB
76	L83	35	(32 or 33) and 37 and 82	EPO; JPO; DERW ENT; IBM_T DB
77	L84	2	(32 or 33) and 82 and 40 and 42	EPO; JPO; DERW ENT; IBM_T DB
78	L85	20	(32 or 33) and 82 and 44	EPO; JPO; DERW ENT; IBM_T DB